Current Mode Control PWM Regulator IC For Switching Power Supplies

Features and Benefits

- TO-220F power package with 30 to 90 W power output
- Current Mode PWM control
- Built-in Random Switching function, reducing EMI noise, and simplifying EMI filters, and therefore reducing cost
- Built-in Slope Compensation function, avoiding subharmonic oscillation
- Built-in Auto Standby function (Input Power, P_{IN} < 30 mW at no load)
- Normal operation: PWM mode
- Light load operation: Standby mode (burst oscillation)
- Built-in Audible Noise Suppression function during Standby mode
- Built-in Startup Circuit, reducing power consumption in standby operation, and eliminating external components.
- Bias-Assist function, improving startup operation, suppressing V_{CC} voltage drop in operation, and allowing use of smaller V_{CC} capacitor

Not to scale

Built-in Leading Edge Blanking function

Continued on the next page...

Package: 6-Pin fully molded TO-220F-6L (FM207)



Description

The STR-W605xS series are power ICs for switching power supplies, incorporating a power MOSFET and a current mode PWM controller IC. Including a startup circuit and a standby function in the controller, the product achieves low power consumption, low standby power, and high cost-effectiveness power supply systems with few external components.

The STR-W605xS internal MOSFET has a V_{DSS} of 650 V (min), and an $R_{DS(on)}$ of 1.9 Ω (max) to 3.95 Ω (max) with a frequency of 67 kHz. Power output is rated at 45 to 90 W at 230 VAC input and 30 to 60 W at wide input range (85 to 265 VAC).

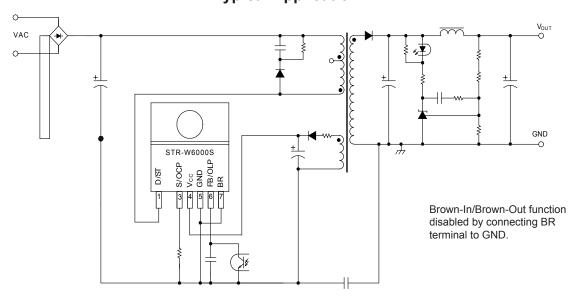
The device is provided in an industry-standard TO-220 package, with heatsink mounting flange and pin 2 removed for increased supply isolation.

Applications:

For switching power supplies used in:

- White goods
- Consumer electronics
- Office automation
- Industrial equipment
- Communication equipment

Typical Application



STR-W605xS-DS

Current Mode Control PWM Regulator IC For Switching Power Supplies

Features and Benefits (continued)

- Two-chip structure, with a controller and a power MOSFET with guaranteed avalanche energy available to simplify surge absorber circuits
- Protection functions:
- Brown-In and Brown-Out Protection function: auto-restart, prevention of excess input current and heat rise at low input voltage
- Overcurrent Protection function (OCP): pulse-by-pulse built-in
- compensation circuit to minimize OCP point variation on AC input voltage
- Overload Protection function (OLP): auto-restart, built-in timer, reduces heat during overload condition, and no external components required
- Overvoltage Protection function (OVP): Auto-restart
- Thermal Shutdown Protection function (TSD): Auto-restart

Selection Guide

Part Number	f _{osc}	MOSFET V _{DSS} (min)	R _{DS(on)} (max)	Р _{оит} * (W)										-D3(011)		Package	Packing
	(KIIZ)	(V)	(Ω)	230 V	Wide												
STR-W6051S			3.95	45	30												
STR-W6052S	67	650	2.8	60	40	TO-220F-6L (Sanken FM207) with pin 2 removed	50 pieces per tube										
STR-W6053S			1.9	90	60	William 2 Terrioved											

^{*} The listed output power is based on the package thermal ratings, and the peak output power can be 120% to 140% of the value stated here. At low output voltage and short duty cycle, the output power may be less than the value stated here.

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Current Mode Control PWM Regulator IC For Switching Power Supplies

Absolute Maximum Ratings¹ Valid at T_A = 25°C, unless otherwise specified

Characteristic	Symbol	Notes	Terminals	Rating	Unit	
			STR-W6051S	1 – 3	5.0	Α
Drain Peak Current ²	I _{Dpeak}	Single pulse	STR-W6052S	1 – 3	7.0	Α
			STR-W6053S	1 – 3	9.5	Α
			STR-W6051S	1 – 3	5.0	Α
Maximum Switching Current ³	I _{DMAX}	$T_A = -20^{\circ}\text{C} \text{ to } 125^{\circ}\text{C}$	STR-W6052S	1 – 3	7.0	Α
			STR-W6053S	1 – 3	9.5	Α
			STR-W6051S	1 – 3	47	mJ
	E _{AS}	Single pulse, V _{DD} = 99 V, L = 20 mH	STR-W6052S	1 – 3	62	mJ
Single Dules Avalenche Energy4		2011111	STR-W6053S	1 – 3	86	mJ
Single Pulse Avalanche Energy ⁴	11/6		STR-W6051S	1 – 3	2.0	Α
	I _{Lpeak}	Single pulse, V _{DD} = 99 V, L = 20 mH	STR-W6052S	1 – 3	2.3	Α
		2011111	STR-W6053S	1 – 3	2.7	Α
S/OCP Terminal Voltage	V _{OCP}			3 – 5	–2 to 6	V
Controller IC (MIC) Supply Input Voltage	V _{CC}			4 – 5	32	V
FB/OLP Terminal Voltage	V _{FB}		337	6 – 5	-0.3 to 14	V
FB/OLP Terminal Sink Current	I _{FB}		7	6 – 5	1.0	mA
BR Terminal Voltage	V _{BR}		722	7 – 5	-0.3 to 7	V
BR Terminal Sink Current	I _{BR}			7 – 5	1.0	mA
		100	STR-W6051S	1 – 3	22.3	W
MOSEET Down Discinsticus	P _{D1}	With infinite heatsink	STR-W6052S	1 – 3	23.6	W
MOSFET Power Dissipation ⁵			STR-W6053S	1 – 3	26.5	W
Il Landen		Without heatsink	4	1-3	1.3	W
Controller IC (MIC) Power Dissipation	P _{D2}	Specified by V _{CC} × I _{CC}	1. 61	4 – 5	0.13	W
Internal Frame Temperature in Operation	T _F			_	-20 to 115	°C
Operating Ambient Temperature	T _{OP}	Maximum recommended internal leadframe temperature, T _F (max) = 105°C		-	–20 to 115	°C
Storage Temperature	T _{stg}			-	-40 to 125	°C
Channel Temperature	T _{ch}			_	150	°C

¹Current characteristics are defined based on IC as sink (+), or source (-).



²Refer to MOSFET Safe Operating Area Curve.

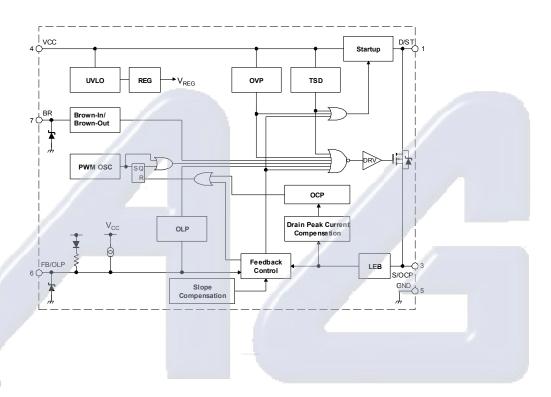
³IDMAX is the drain current on the D/ST pin determined by the drive voltage of the IC and the threshold voltage, Vth, of the MOSFET.

⁴Refer to MOSFET Avalanche Energy Derating Coefficient Curve.

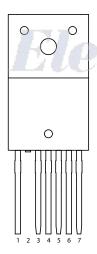
⁵Refer to MOSFET Temperature versus Power Dissipation Curve.

Current Mode Control PWM Regulator IC For Switching Power Supplies

Functional Block Diagram



Pin-out Diagram



Terminal List Table

Number	Name	Function
1	D/ST	MOSFET drain, and input for startup current
2	-	(Pin removed)
3	S/OCP	MOSFET source, and input for Overcurrent Protection detection signal
4	V _{CC}	Input for power supply for control circuit
5	GND	Ground
6	FB/OLP	Input for constant voltage control signal, and input for Overload Protection signal
7	BR	Input for Brown-In and Brown-Out Protection detection voltage

Current Mode Control PWM Regulator IC For Switching Power Supplies

Electrical Characteristics¹ Valid at V_{CC} = 18 V, T_A = 25°C, unless otherwise specified

V _{CC(ON)}	4 – 5	12.0			
		13.8	15.3	16.8	V
V _{CC(OFF)}	4 – 5	7.3	8.1	8.9	V
I _{CC(ON)}	4 – 5	-	_	2.5	mA
V _{ST(ON)}	4 – 5	-	40	-	V
I _{STARTUP}	4 – 5	-3.9	-2.5	-1.1	mA
V _{CC(BIAS)}	4 – 5	8.5	9.5	10.5	V
f _{OSC(av)}	1 – 5	60	67	74	kHz
Δf	1 – 5	_	5	_	kHz
D _{MAX}	1 – 5	63	71	79	%
t _{BW}	_	-	390	<u> </u>	ns
D _{PC}	_	- /	18	-	mV/μs
D _{DPC}	_	-//	36	-	%
V _{OCP(L)}	3 – 5	0.70	0.78	0.86	V
V _{OCP(H)}	3 – 5	0.79	0.88	0.97	V
I _{FB(MAX)}	6 – 5	-340	-230	-150	μΑ
I _{FB(MIN)}	6 – 5	-30	-15	-7	μA
V _{FB(OFF)}	6 – 5	0.85	0.95	1.05	V
V _{FB(OLP)}	6 – 5	7.3	8.1	8.9	V
I _{CC(OLP)}	4 – 5	-	300	-	μΑ
t _{OLP}	1 – 5	54	68	82	ms
V _{FB(CLAMP)}	6 – 5	11	12.8	14	V
V _{BR(IN)}	7 – 5	5.2	5.6	6	V
V _{BR(OUT)}	7 – 5	4.45	4.8	5.15	V
V _{BR(CLAMP)}	7 – 5	6	6.4	7	V
V _{BR(DIS)}	7 – 5	0.3	0.48	0.7	V
V _{CC(OVP)}	4 – 5	26	29	32	V
T _{J(TSD)}	-	130	_	_	°C
	Icc(on) Vst(on) Istartup Vcc(bias) fosc(av) Af Dmax tbw Dpc Ddpc Vocp(l) Vocp(h) Ifb(max) Ifb(min) Vfb(off) Vfb(clamp) Vbr(clamp) Vocc(ovp)	Icc(ON)	I _{CC(ON)} 4 - 5 - V _{ST(ON)} 4 - 5 - I _{STARTUP} 4 - 5 -3.9 V _{CC(BIAS)} 4 - 5 8.5 f _{OSC(av)} 1 - 5 60 Δf 1 - 5 - D _{MAX} 1 - 5 63 t _{BW} - - D _{PC} - - V _{OCP(L)} 3 - 5 0.70 V _{OCP(L)} 3 - 5 0.79 I _{FB(MAX)} 6 - 5 -340 I _{FB(MAX)} 6 - 5 -340 I _{FB(MIN)} 6 - 5 0.85 V _{FB(OF)} 6 - 5 7.3 I _{CC(OLP)} 4 - 5 - t _{OLP} 1 - 5 54 V _{FB(CLAMP)} 7 - 5 5.2 V _{BR(OUT)} 7 - 5 6 V _{BR(DIS)} 7 - 5 0.3 V _{CC(OVP)} 4 - 5 26 T _J (TSD) - 130	Icc(ON)	I _{CC(ON)}

¹Current characteristics are defined based on IC as sink (+), or source (-).

MOSFET Electrical Characteristics Valid at T_A = 25°C, unless otherwise specified

Characteristic	Symbol	Device	Terminal	Min.	Тур.	Max.	Unit
Drain-to-Source Breakdown Voltage	V _{DSS}	_	1 – 3	650	_	_	V
Drain Leakage Current	I _{DSS}	_	1 – 3	_	_	300	μΑ
		STR-W6051S	1 – 3	_	_	3.95	Ω
On-Resistance	R _{DS(on)}	STR-W6052S	1 – 3	_	_	2.8	Ω
		STR-W6053S	1 – 3	_	_	1.9	Ω
Switching Time	t _f	_	1 – 3	_	_	250	ns
		STR-W6051S	_	_	_	2.63	°C/W
Thermal Resistance*	R _{θchF}	STR-W6052S	_	_	_	2.26	°C/W
		STR-W6053S	_	_	_	1.95	°C/W

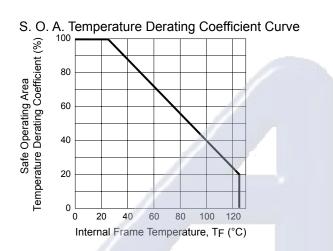
^{*}Between channel and internal frame.



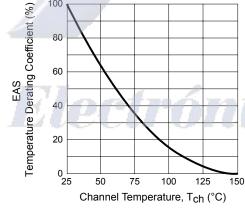
 $^{^{2}}V_{CC(BIAS)} > V_{CC(OFF)}$.

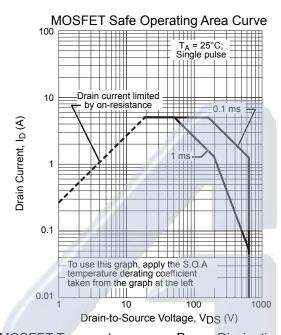
Current Mode Control PWM Regulator IC For Switching Power Supplies

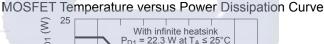
Characteristic Performance STR-W6051S

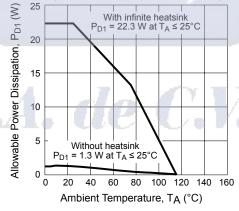


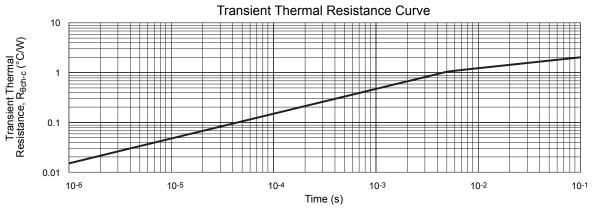






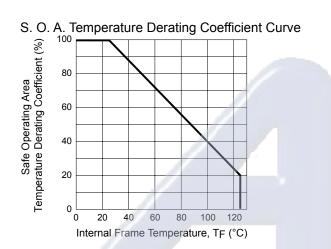




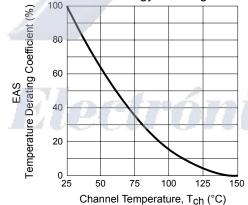


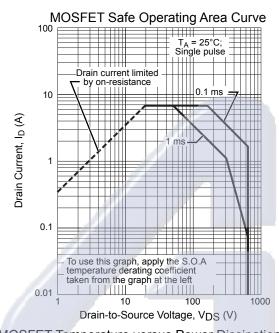
Current Mode Control PWM Regulator IC For Switching Power Supplies

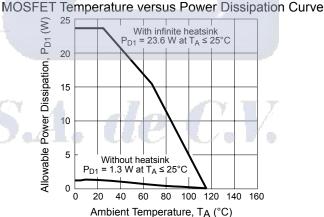
Characteristic Performance STR-W6052S

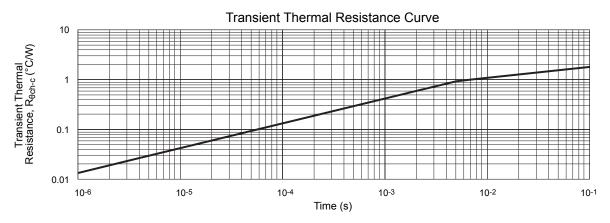










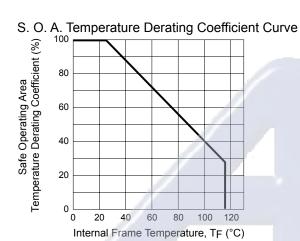


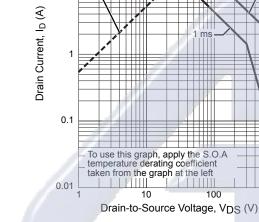
Current Mode Control PWM Regulator IC For Switching Power Supplies

Drain current limited

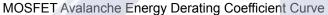
by on-resistance

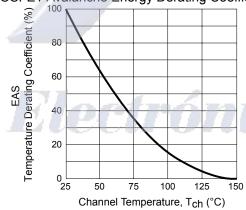
Characteristic Performance STR-W6053S





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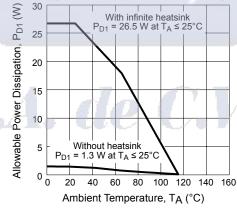


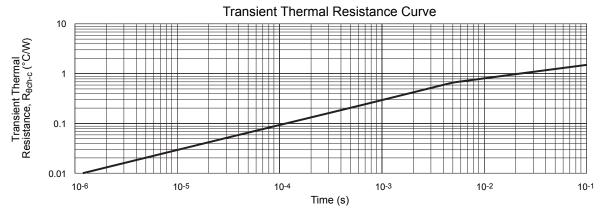
MOSFET Safe Operating Area Curve

T_A = 25°C; Single pulse

0.1 ms

1000

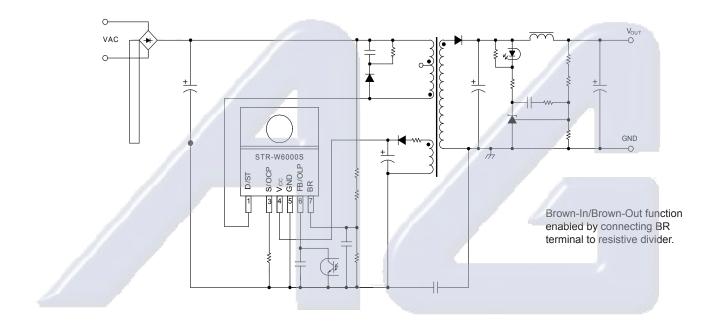






Current Mode Control PWM Regulator IC For Switching Power Supplies

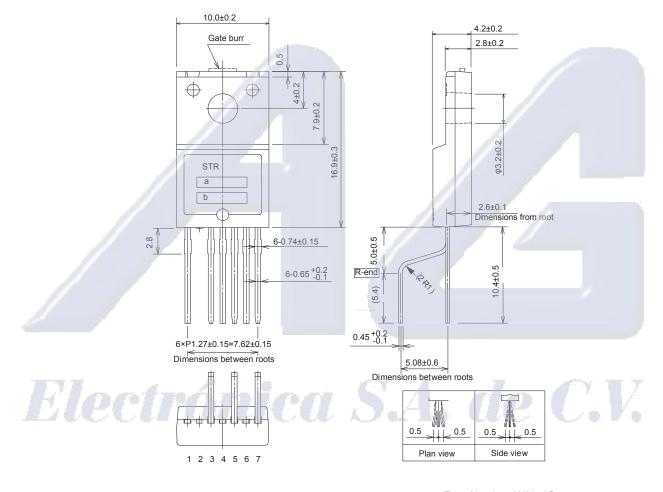
Typical Application



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Current Mode Control PWM Regulator IC For Switching Power Supplies

Package Outline Drawing, TO-220F-6L (FM207)



Leadform: 2003

Material of terminal: Cu Treatment of terminal: Solder plating (Pb-free) Weight: Approximately 2.3 g Dashed line at Gate Burr indicates protrusion of 0.3 mm (max) Unit: mm a. Type Number: W6051S

b. Lot Number:

1st letter: Last digit of year

2nd letter: Month

1 to 9 for Jan. to Sept.

O for Oct.

N for Nov.

D for Dec.

3rd and 4th letter: Day of month

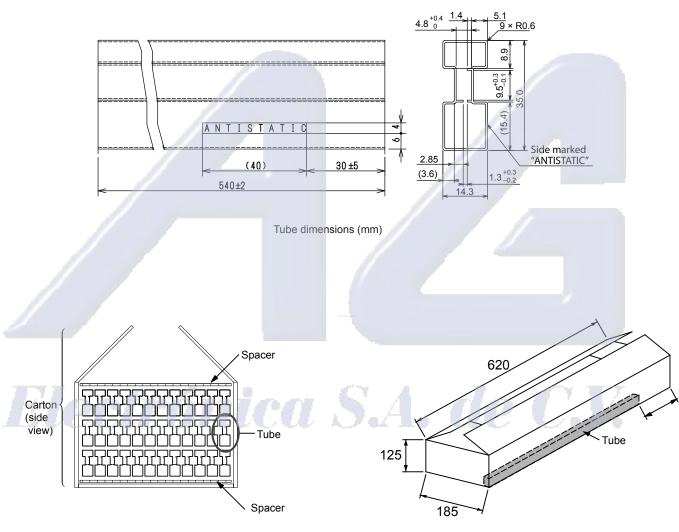
5th letter: Sanken Registration Number

Leadframe plating Pb-free. Device composition compliant with the RoHS directive.



Current Mode Control PWM Regulator IC For Switching Power Supplies

Packing Specifications



Carton dimensions (mm)

Capacity:

36 tubes per carton (3 rows, 12 tubes per row)

50 pieces per tube

1800 pieces maximum per carton



Current Mode Control PWM Regulator IC For Switching Power Supplies

Because reliability can be affected adversely by improper storage environments and handling methods, please observe the following cautions.

Cautions for Storage

- Ensure that storage conditions comply with the standard temperature (5°C to 35°C) and the standard relative humidity (around 40% to 75%); avoid storage locations that experience extreme changes in temperature or humidity.
- Avoid locations where dust or harmful gases are present and avoid direct sunlight.
- Reinspect for rust on leads and solderability of products that have been stored for a long time.

Cautions for Testing and Handling

When tests are carried out during inspection testing and other standard test periods, protect the products from power surges from the testing device, shorts between the product pins, and wrong connections.

Remarks About Using Silicone Grease with a Heatsink

- When silicone grease is used in mounting this product on a heatsink, it shall be applied evenly and thinly. If more silicone grease than required is applied, it may produce excess stress.
- Volatile-type silicone greases may crack after long periods of time, resulting in reduced heat radiation effect. Silicone grease with low consistency (hard grease) may cause cracks in the mold resin when screwing the product to a heatsink.
- Our recommended silicone greases for heat radiation purposes, which will not cause any adverse effect on the product life, are indicated below:

Type	Suppliers
G746	Shin-Etsu Chemical Co., Ltd.
YG6260	Momentive Performance Materials Holding, Inc.
SC102	Dow Corning Toray Co., Ltd.

Soldering

- Leadframe temperature, T_F, should not exceed 115°(max)
- When soldering the products, please be sure to minimize the working time, within the following limits: 260±5°C 10 s

350±5°C 3 s (solder iron)

 To avoid an internal chip damaged, soldering on each of lead-pins should be at a distance of at least 2 mm away from the body of the products

Assembly

 Recommended screw torque through the mounting tab is 0.588 to 0.785 N • m (6 to 8 kgf • cm).

Electrostatic Discharge

- When handling the products, the operator must be grounded. Grounded wrist straps worn should have at least 1 MΩ of resistance from the operator to ground to prevent shock hazard, and it should be placed near the operator.
- Workbenches where the products are handled should be grounded and be provided with conductive table and floor mats.
- When using measuring equipment such as a curve tracer, the equipment should be grounded.
- When soldering the products, the head of soldering irons or the solder bath must be grounded in other to prevent leak voltages generated by them from being applied to the products.
- The products should always be stored and transported in Sanken shipping containers or conductive containers, or be wrapped in aluminum foil.

